

1N5817WS THRU 1N5819WS

SCHOTTKY BARRIER RECTIFIERS

Reverse Voltage: 20V TO 40V

Forward Current: 1A

FEATURES

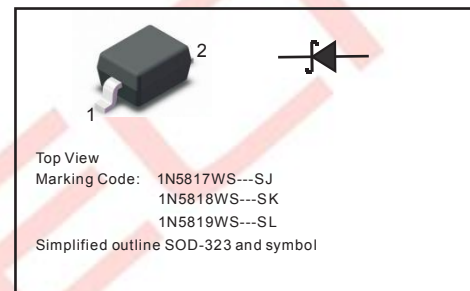
- ◆ Metal silicon junction, majority carrier conduction
- ◆ Guarding for overvoltage protection
- ◆ Low power loss, high efficiency
- ◆ High current capability
- ◆ low forward voltage drop
- ◆ High surge capability
- ◆ For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications

MECHANICAL DATA

- ◆ Case: SOD-323
- ◆ Terminals: Solderable per MIL-STD-750, Method 2026
- ◆ Approx. Weight: 5.48mg / 0.00019oz

PINNING

PIN	DESCRIPTION
1	Cathode
2	Anode



Maximum Ratings and Electrical characteristics

Ratings at 25 °C ambient temperature unless otherwise specified.

Parameter	Symbols	1N5817WS	1N5818WS	1N5819WS	Units
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	20	30	40	V
Maximum RMS voltage	V_{RMS}	14	21	28	V
Maximum DC Blocking Voltage	V_{DC}	20	30	40	V
Maximum Average Forward Rectified Current	$I_{F(AV)}$	1			A
Peak Forward Surge Current, 8.3ms Single Half Sine-wave Superimposed On Rated Load (JEDEC method)	I_{FSM}	25			A
Maximum Instantaneous Forward Voltage at 1 A at 3 A	V_F	0.45 0.75	0.55 0.875	0.6 0.9	V
Maximum Instantaneous Reverse Current at $T_A = 25^{\circ}C$ Rated DC Reverse Voltage $T_A = 100^{\circ}C$	I_R	1 10			mA
Typical Junction Capacitance	C_j	110			pF
Storage and Operating Junction Temperature Range	T_j, T_{stg}	-55 ~ +150			$^{\circ}C$

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Typical Characteristics Curves

Fig.1 Forward Current Derating Curve

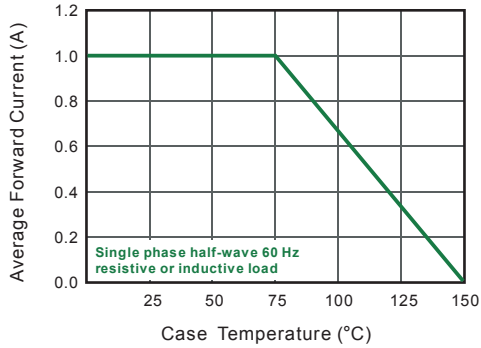


Fig.2 Typical Reverse Characteristics

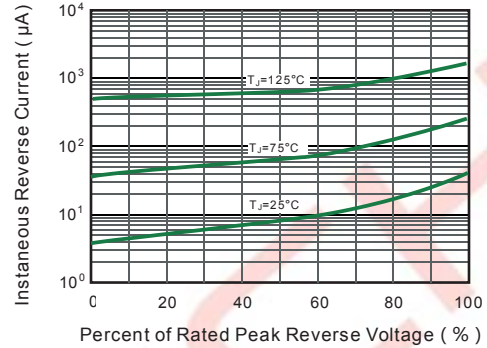


Fig.3 Typical Forward Characteristic

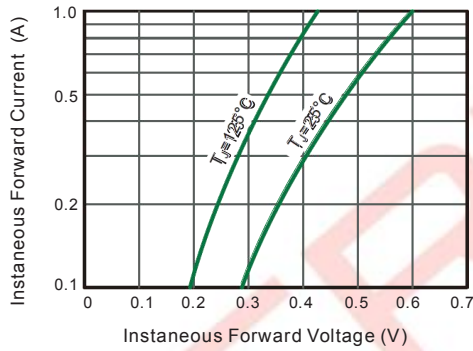


Fig.4 Typical Junction Capacitance

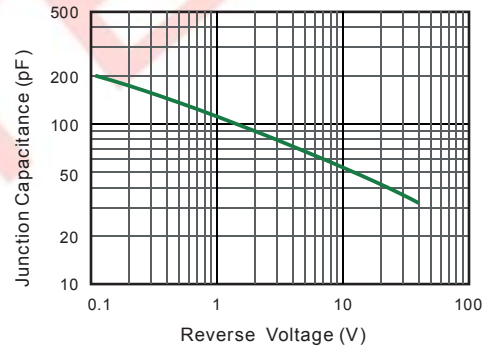
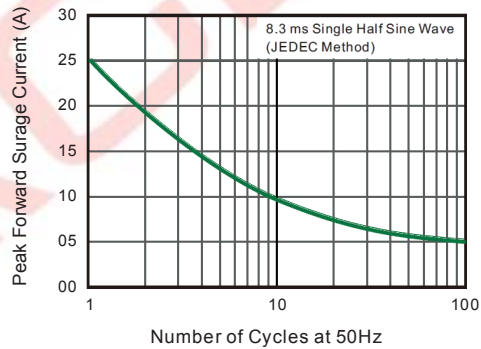


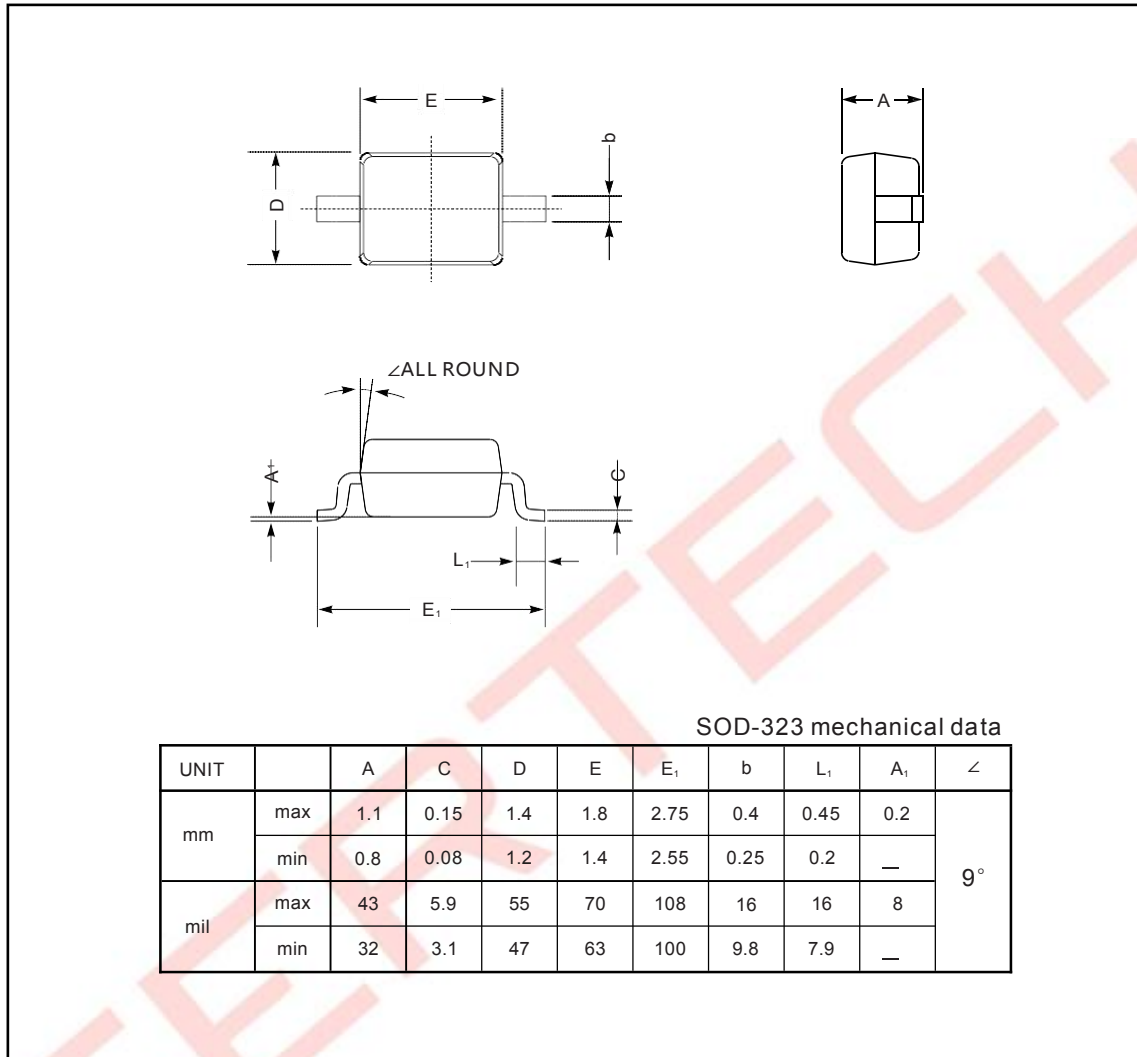
Fig.5 Maximum Non-Repetitive Peak Forward Surge Current



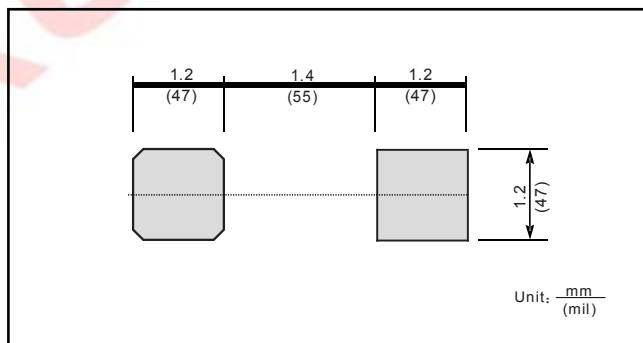
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Package Outline

SOD-323



The recommended mounting pad size



Marking

Type number	Marking code
1N5817WS	SJ
1N5818WS	SK
1N5819WS	SL